



DC to 4500 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

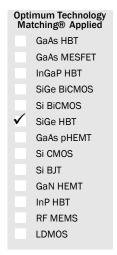
Package: SOT-89

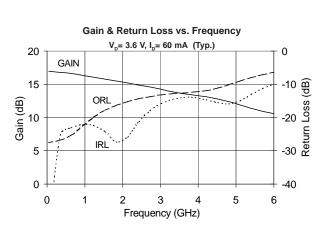




Product Description

The SGA5389Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high F_T and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.





Features

- High Gain: 15.4dB at 1950MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

| Parameter | Specification | | | Unit | Condition | | |
|-----------------------------------------|---------------|------|------|-------|-----------|--|--|
| Parameter | Min. | Тур. | Max. | Ullit | Condition | | |
| Small Signal Gain | 14.8 | 16.4 | 18.0 | dB | 850MHz | | |
| | | 15.4 | | dB | 1950MHz | | |
| | | 14.9 | | dB | 2400 MHz | | |
| Output Power at 1dB Compression | | 16.3 | | dBm | 850MHz | | |
| | | 15.0 | | dBm | 1950 MHz | | |
| Output Third Intercept Point | | 31.5 | | dBm | 850MHz | | |
| | | 28.1 | | dBm | 1950MHz | | |
| Bandwidth Determined by Return Loss | | 4500 | | MHz | >10dB | | |
| Input Return Loss | | 27.6 | | dB | 1950MHz | | |
| Output Return Loss | | 15.9 | | dB | 1950 MHz | | |
| Noise Figure | | 3.5 | | dB | 1950MHz | | |
| Device Operating Voltage | 3.1 | 3.6 | 4.1 | V | | | |
| Device Operating Current | 54 | 60 | 66 | mA | | | |
| Thermal Resistance (Junction - Lead) | | 97 | | °C/W | | | |

Test Conditions: $V_S = 8V$, $I_D = 60 \text{ mA}$ Typ., OIP_3 Tone Spacing = 1MHz, P_{OLIT} per tone = 0 dBm, $R_{BIAS} = 75 \Omega$, $T_L = 25 \,^{\circ}\text{C}$, $Z_S = Z_L = 50 \Omega$



Absolute Maximum Ratings

| Parameter | Rating | Unit |
|----------------------------------------|------------|------|
| Max Device Current (I _D) | 120 | mA |
| Max Device Voltage (V _D) | 5 | V |
| Max RF Input Power | +16 | dBm |
| Max Junction Temp (T _J) | +150 | °C |
| Operating Temp Range (T _L) | -40 to +85 | °C |
| Max Storage Temp | +150 | °C |
| Moisture Sensitivity Level | MSL 2 | |

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression: $I_DV_D\!<\!(T_J\!-\!T_L)/\,R_{TH},\,j\text{-}I$



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

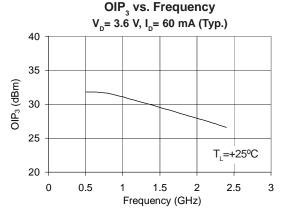
RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

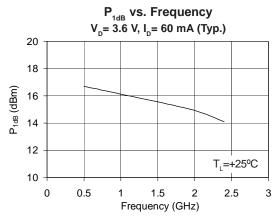
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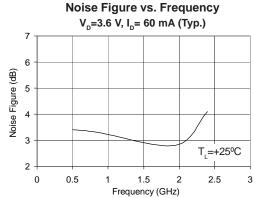
Typical Performance at Key Operating Frequencies

| Parameter | Unit | 100 | 500 | 850 | 1950 | 2400 | 3500 |
|------------------------------------|------|------|------|------|------|------|------|
| | | MHz | MHz | MHz | MHz | MHz | MHz |
| Small Signal Gain | dB | 16.9 | 16.7 | 16.4 | 15.4 | 14.9 | 13.7 |
| Output Third Order Intercept Point | dBm | | 31.8 | 31.5 | 28.1 | 26.6 | |
| Output Power at 1dB Compression | dBm | | 16.7 | 16.3 | 15.0 | 14.1 | |
| Input Return Loss | dB | 37.5 | 24.0 | 22.2 | 27.6 | 21.6 | 14.1 |
| Output Return Loss | dB | 27.8 | 26.2 | 23.4 | 15.9 | 14.4 | 12.7 |
| Reverse Isolation | dB | 20.5 | 20.6 | 20.8 | 21.6 | 21.7 | 21.1 |
| Noise Figure | dB | | 3.4 | 3.3 | 2.8 | 4.1 | |

 $Test \ Conditions: \ V_S=8V, \ I_D=60 \ mA \ Typ., \ OIP_3 \ Tone \ Spacing=1 \ MHz, \ P_{OUT} \ per \ tone=0 \ dBm, \ R_{BIAS}=75 \ \Omega, \ T_L=25 \ ^{\circ}C, \ Z_S=Z_L=50 \ \Omega$



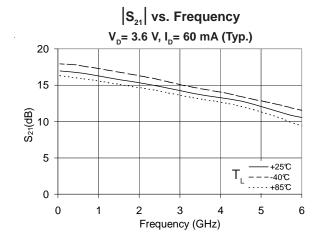


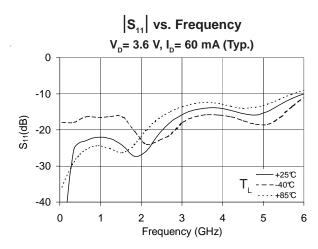


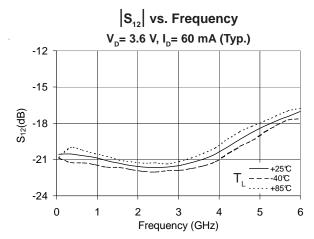


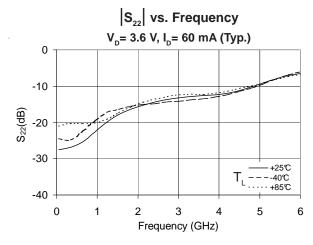


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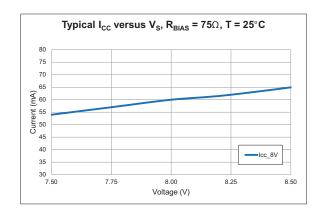


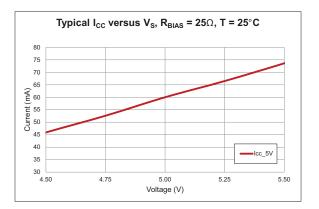


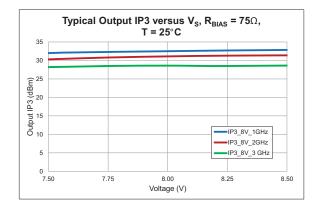


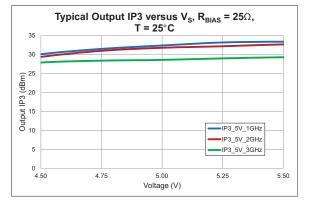


Typical Performance versus Power Supply Variations





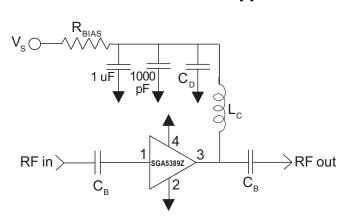






| Pin | Function | Description |
|------|-------------|---------------------------------------------------------------------------------------------------------------------------------|
| 1 | RF IN | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. |
| 2, 4 | GND | Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible. |
| 3 | RF OUT/BIAS | RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation. |

Application Schematic

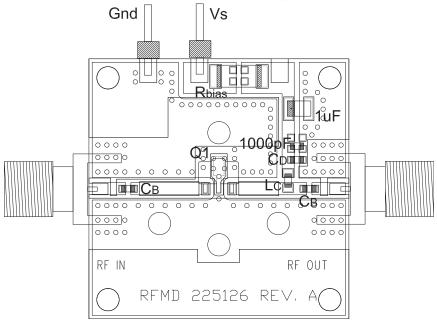


Application Circuit Element Values

| Reference | | Frequency (Mhz) | | | | | | |
|----------------|--------|-----------------|-------|-------|-------|--|--|--|
| Designator | 500 | 850 | 1950 | 2400 | 3500 | | | |
| C _B | 220 pF | 100 pF | 68 pF | 56 pF | 39 pF | | | |
| C _D | 100 pF | 68 pF | 22 pF | 22 pF | 15 pF | | | |
| L _c | 68 nH | 33 nH | 22 nH | 18 nH | 15 nH | | | |

| Recommended Bias Resistor Values for I_D =60mA R_{BIAS} =(V_S - V_D) / I_D | | | | |
|-----------------------------------------------------------------------------------------------------|------|------|------|-------|
| Supply Voltage(V _s) | 6 V | 8 V | 10 V | 12 V |
| R _{BIAS} | 43 Ω | 75 Ω | 110Ω | 150 Ω |
| Note: $\mathbf{R}_{\scriptscriptstyle{\mathrm{BIAS}}}$ provides DC bias stability over temperature. | | | | |

Evaluation Board Layout

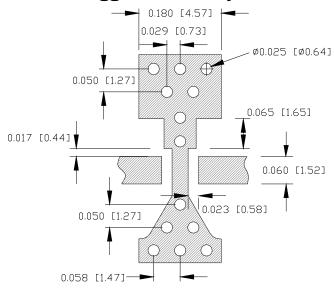


Mounting Instructions:

- 1. Solder the copper pad on the backside of the device package to the ground plane.
- 2. Use a large ground pad area with many plated through-holes as shown.
- 3. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31mil thick FR-4 board with 1 ounce copper on both sides.

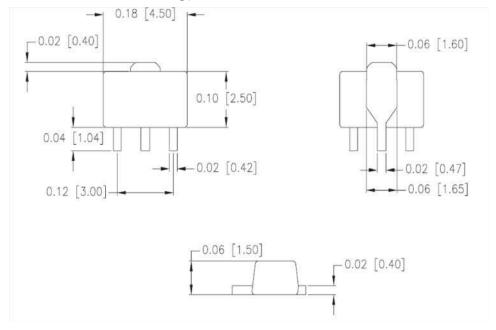


Suggested Pad Layout



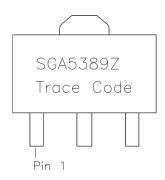
Package Drawing

Dimensions in inches (millimeters)
Refer to drawing posted at www.rfmd.com for tolerances.





Part Identification



Ordering Information

| Ordering Code | Description |
|---------------|---------------------------------------------------|
| SGA5389Z | 13" Reel with 3000 pieces |
| SGA5389ZSQ | Sample bag with 25 pieces |
| SGA5389ZSR | 7" Reel with 100 pieces |
| SGA5389ZPCK1 | 850MHz, 8V Operation PCBA with 5-piece sample bag |